RDA1846



SINGLE CHIP TRANSCEIVER FOR WALKIE TALKIE Rev. 1.2-Dec. 2009

1. General Description

The RDA1846 is a highly integrated single-chip transceiver for Walkie Talkie applications. It totally realizes the translation from RF carrier to voice in the RX path and from voice to RF carrier in the TX path, requiring only one micro controller.

The RDA1846 has a powerful digital signal processor, which makes it have optimum voice quality, flexible function options, and robust performance under varying reception conditions.

The RDA1846 can be tuned to the worldwide frequency band for Walkie Talkie from 400MHz to 500MHz and especially from 134MHz to 174MHz which meets the frequency band of weather broadcast.

The transceiver uses the CMOS process with a package size of 5X5mm. By virtue of its high integration, it requires the least external components and eliminates the complicated design of sensitive RF circuits on PCB.

1.1 Features

- CMOS single-chip fully-integrated transceiver
- Fully integrated frequency synthesizer and VCO
- Support worldwide frequency band
 - ➢ 134MHz ~ 174MHz
 - > 400MHz ~ 500MHz
- 12.5KHz, 25KHz channels
- Support multiple XTAL clocks
 - > 12.8/25.6Mhz
 - > 13/26Mhz
- Digital auto frequency control (AFC)
- Digital auto gain control (AGC)
- Selectable pre/de-emphasis
- Received signal strength indicator (RSSI)
- VOX and SQ
- Build-in CTCSS/CDCSS generator and judgment
 - > CTCSS with 120/180 /240 degree phase shift
 - > 23/24 bit programmable DCS code



- DTMF and programmable in-band dual tone
- Programmable in-band single tone transmitter
- Auto RX/TX/SLEEP state switching
- 8 GPIOs
- 3-wire/4-wire/I²C serial control bus interface
- On chip 8 dBm PA
- Analog and digital volume control
- Directly support 32Ω resistance loading
- 3.3 to 4.8 V supply voltage with Integrated LDO
- 5X5 mm 32 pin QFN package

1.2 Applications

- Cellular handsets
- Family radio services
- Walkie Talkies

Copyright © RDA Microelectronics Inc. 2009. All rights are reserved.

The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA.

2. Table of Contents

1.	General Descrip	tion1
	1.1 Featur	es1
	1.2 Applic	ations1
2.	Table of Conten	ts2
3.	Functional Desc	ription3
	3.1 RF inp	ıt and output
	3.2 Voice i	nput and output4
	3.3 Synthe	sizer4
	3.4 XTAL	Clock4
	3.5 DSP ft	nctions4
	U	ated LDO
	3.7 Serial	Control Interface
4.		cteristics
5.		nitter Characteristics6
6.		e Characteristics
7.		
8.	Application Dia	gram
9.		
10.		g Condition
11.	Change List	
12.	Contact Inform	ation16
		Colt

Copyright © RDA Microelectronics Inc. 2009. All rights are reserved. The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA.

3. Functional Description



The RDA1846 transceiver features very low solution cost and reduced complexity. As shown in Fig.3.1, to totally complete the translation from RF carrier to voice in the RX path and from voice to RF carrier in the TX path, the chip integrates nearly all the functional blocks including RF and base band analog blocks and digital signal processor. It requires only one micro controller and a few external components to realize a walkie-talkie.

A powerful integrated DSP accomplishes both the demodulation and modulation of the FM signal. Besides, standard walkie-talkie features such as CTS, CDS, VOX and SQ etc. are provided through the 8 GPIOs of the chip. Especially, by virtue of the state-of-the-art CMOS technology advanced algorithms such as AFC, AGC, RSSI and SNR calculations are realized in the DSP, which guarantees the high receiving and transmitting quality while still consumes a low power. Flexible RX/TX/SLEEP auto switching function from the DSP further reduces the average power consumptions.

LDOs are also integrated in the chip which further reduces the BOMs.

All interface pins of the chip will be shortly explained below. For details, refer to the 'RDA 1846 programming guide'.

3.1 RF input and output

The chip can receive and transmit RF signals from 400 to 500MHz and from 134 to 174MHz which cover most of the walkie-talkie frequency bands around the world and the weather broadcast band. For the RF input, a direct-in connection from the antenna to the LNA input pin through a switch is suggested which means no input impedance matching is needed for the receive band. For the RF out, a pa diver can deliver no more than 8 dBm power to PA. PA bias voltage from 1.5V~2.8V for the power amplifier can be supplied from the PABIAS pin.

The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA. Page 3 of 16

3.2 Voice input and output

In the RX path, the voice signal after demodulation is sent to the internal DAC which can directly drive a 32Ω resistance loading through AC coupling. In the TX path, microphone signal can be sent into the chip through AC coupling capacitors.

3.3 Synthesizer

The frequency synthesizer generates the local oscillator signal. All building blocks are fully integrated without any external components. LO frequency can be programmed through the serial interface by the MCU. <u>(How to select frequency band and program LO frequency, refer to the programming guide)</u>

3.4 XTAL Clock

The RDA1846 supports XTAL clocks such as 12.8 MHz, 13 MHz, 25.6 MHz and 26 MHz. The internal XTAL oscillator can also be bypassed thus TCXO clock with appropriate amplitude can be sent into the chip directly. <u>(How to configure the internal XTAL oscillator, refer to the programming guide)</u>

3.5 DSP functions

The DSP accomplishes the demodulation and modulation of the FM signal. Standard walkie-talkie features such as CTS, CDS, VOX and SQ etc. are provided through the 8 GPIOs. <u>(How to configure the GPIOs, refer to the programming guide)</u>

3.6 Integrated LDO

LDOs are integrated on chip which eliminates using one LDO chip on the PCB. Supply voltage for the chip is suggested to be within 3.3V~4.8V. <u>A common share of the supply voltage for RDA1846 and other chips or on board circuits are not appropriate and thus not recommended.</u>

3.7 Serial Control Interface

A 3-wire/4-wire/I²C serial interface is provided for host IC to read and write RDA1846 control registers. *(For details of the serial control interface, refer to the programming guide)*.

4. Electrical Characteristics

Table 4-1	DC Electrical Specification (Recommended Operation Conditions):
	Be Lieundal operation (Recommended operation conditions).

SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNIT
AVDD	Supply Voltage from battery or LDO	3.3	3.3	4.8	V
T _{amb}	Ambient Temperature	-25	27	+85	°C
VL	CMOS Low Level Input/output Voltage	0		0.3	V
V _H	CMOS High Level Input/output Voltage	2.7		3	V
V _{TH}	CMOS Threshold Voltage		1.5		V

Table 4-2 DC Electrical Specification (Absolute Maximum Ratings):

SYMBOL	DESCRIPTION	MIN	TYP	MAX	UNIT
T _{amb}	Ambient Temperature	-40		+90	°C
I _{IN}	Input Current	-10		+10	mA
V _{IN}	Input Voltage	-0.3	いい	3.3	V
V _{Ina}	LNA Input Level	K		+10	dBm

Table 4-3 Power consumption specification

(AVDD = 3.3 V, T_A = -25 to 85 $^\circ\!\!\!\mathrm{C}$, unless otherwise specified)

STATE	DESCRIPTION	Condition	ТҮР	UNIT
I _{Rx}	Continue Receive	RXON=1,PDN=1	55	mA
I _{Tx}	Continue Transmit	TXON=1,PDN=1	50	mA
I _{sleep}	Deep sleep	PDN=0	40	μA

5. Receiver/Transmitter Characteristics

Table 5-1 Receiver Characteristics

(AVDD = 3.3 V, TA = -25 to 85 °C, unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT		
General spec	General specifications							
Fin	Input Frequency Range1		400		520	MHz		
	Input Frequency Range2		134		174	MHz		
	Input Frequency Range3		200		260	MHz		
NF	Noise Figure	Max RX Gain		3		dB		
IP3 _{in}	Input IP3	Max RX Gain	-10	-6	0	dBm		
SEN	Sensitivity	12.5kHz channel, 12dB SINAD	-125	-124	-123	dBm		
ACS	Adjacent Channel Selectivity	\pm 12.5KHz	65	66	67	dB		
IR	Image rejection		60	70		dB		
	Blocker	> 1MHz		85		dB		
	Voice distortion			1.5		%		

Table 5-2 Transmit Characteristics

(AVDD = 3.3 V, TA = -25 to 85°C, unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
General specifi	cations	XV				
Fout	Output Frequency Range1		400		520	MHz
	Output Frequency Range2		134		174	MHz
	Output Frequency Range3		200		260	MHz
POUT	Output Power		-2	5	8	dBm
SINAD/SNR				48/53		dB
ACP	Adjacent channel power			-67		dBc
	Modulation sensitivity	1.5kHz frequency offset		13		mV
	Voice distortion			0.5		%
	Modulation limitation			2.2	2.5	kHz

6. Control Interface Characteristics

Refer to the 'RDA1846 programming guide'.

opline

7. Pins Description



SYMBOL	PIN	DESCRIPTION	
AVDD	1	Power supply	
SCLK	2	Clock input for serial control bus	
SDIO	3	Data input/output for serial control bus	
AVDD	4	Power supply	
XTAL1	5	Oscillator pin 1	
XTAL2	6	Oscillator pin 2	
		Control Interface select	
MODE	7	When MODE = V_L , I^2C Interface is select	
		When MODE = V_H , SPI Interface is select	
SENB	8	Latch enable (active low) input for serial control bus	
AFOUT	9	Audio signal output to speaker	
NC*	10	No connection	
MIC_IN	11	MIC input	
Сс	12	Compensation capacitor connection pin	
AVDD	13	Power supply	
NC*	14	No connection	
RFIN	15	RF signal input	
AVDD	16	Power supply	
NC*	17	No connection	
RFOUT	18	RF signal output	
NC*	19	No connection	
NC*	20 시	No connection	
AVDD	21	Power supply	
PABIAS	22	PA bias supply for PA	
AVDD	23	Power supply	
PDN	24	Chip enable, low active	
00107	0.5	Gpio7 / vox	
GPIO7	25	(When Gpio7= V_H , vox is active; else V_L)	
	00	Gpio6 / sq	
GPIO6	26	(When Gpio6= V_H , sq is active; else V_L)	
00105	07	Gpio5 / txon	
GPIO5	27	(When Gpio5=V _H , txon is active; else V_L)	
		Gpio4 / rxon	
GPIO4	28	(When Gpio4= V_H , rxon is active; else V_L)	
		Gpio3 / sdo	
GPIO3	29	(Gpio3=V _H or V _L , it is the output register data in 4 wire control	
		interface mode)	
	20	Gpio2 / int	
GPIO2	30	(When Gpio2=V _H , int is active; else V_L)	

Table 7-1 RDA1846 Pins Description

The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA. Page 9 of 16

GPIO1	31	Gpio1 / code_in / code_out (Gpio1=V _H or V _L , it is the input/output code data)
GPIO0	32	Gpio0 / css_in / css_out (Gpio0=V _H or V _L , it is the input/output CTCSS/CDCSS signal)

*Attention: all NC pins should be floating. Do not connect it to GND!

ontheath

8. Application Diagram



Notes:

- 1 U1: RDA1846 Chip;
- 2 AVDD: Power Supply for RDA1846 (3.3~4.8V);
- 3 AVDD_PA: Power Supply for RF PA, its voltage depends on the actual PA design;
- 4 C0~C11: AVDD decouple capacitance (1nF and 100nF in pairs), as close to AVDD pin as possible;
- 5 CA1~CA2: Audio AC couple capacitance (~47uF);
- 6 Cc: Compensation capacitance connected between pin Cc and GND (~47uF);
- 7 Crf: RF AC couple capacitance (~150pF);
- 8 CX1~CX2: XTAL oscillator load capacitance. Its value depends on the chosen XTAL (*if using external TCXO, clk* should be sent into pin XTAL1 with Vpp about 1.5V, and pin XTAL2 should be connected to GND);
- 8 R0~R1(optional): resistors for serial interface wire SDIO and SCLK (~10kΩ);
- 10 Pins NC(10,14,17,19,20) should be floating;
- 11 External vox detection circuit is optional;

The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA. Page 11 of 16

9. Package Outline



32-Pin 5x5 Quad Flat No-Lead (QFN)

10. Solder Mounting Condition



Classification Reflow Profile

Table 10-1	Classificatio	n Reflov	v Profiles
	olassincatio	in renov	V I I OIIIC3

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Average Ramp-Up Rate (T _{Smax} to T _p)	3 °C/second max.	3 °C/second max.
Preheat 🔶 🌔		
-Temperature Min (T _{smin})	100 °C	150 °C
-Temperature Max (T _{smax})	100 °C	200 °C
-Time (t _{smin} to t _{smax})	60-120 seconds	60-180 seconds
Time maintained above:		
-Temperature (T _L)	183 °C	217°C
-Time (t _L)	60-150seconds	60-150 seconds
Peak /Classification Temperature(T _p)	See Table-II	See Table-III
Time within 5 °C of actual Peak Temperature (t _p)	10-30 seconds	20-40 seconds
Ramp-Down Rate	6 °C/second max.	6 °C/seconds max.
Time 25 [°] C to Peak Temperature	6 minutes max.	8 minutes max.

The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA. Page 13 of 16

Package Thickness	Volume mm ³ <350	Volume mm ³ ≥350
<2.5mm	240 + 0/-5 ° C	225 + 0/-5 ° C
≥2.5mm	225 + 0/-5 ° C	225 + 0/-5 ° C

Table 10-2 SnPb Eutectic Process – Package Peak Reflow Temperatures

Table 10-3 Pb-free Process – Package Classification Reflow Temperatures

Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6mm	260 + 0 ° C *	260 + 0 ° C *	260 + 0 ° C *
1.6mm – 2.5mm	260 + 0 ° C *	250 + 0 ° C *	245 + 0 ° C *
≥2.5mm	250 + 0 ° C *	245 + 0 ° C *	245 + 0 ° C *
*Tolerance : The device manufacturer/supplier shall assure process compatibility up to and			

*Tolerance : The device manufacturer/supplier **shall** assure process compatibility up to and including the stated classification temperature(this mean Peak reflow temperature + 0 °C. For example 260+ 0 °C) at the rated MSL Level.

Note 1: All temperature refer topside of the package. Measured on the package body surface.

- **Note 2:** The profiling tolerance is + 0 ° C, X ° C (based on machine variation capability)whatever is required to control the profile process but at no time will it exceed 5 ° C. The producer assures process compatibility at the peak reflow profile temperatures defined in Table –III.
- Note 3: Package volume excludes external terminals(balls, bumps, lands, leads) and/or non integral heat sinks.
- **Note 4:** The maximum component temperature reached during reflow depends on package the thickness and volume. The use of convection reflow processes reduces the thermal gradients between packages. However, thermal gradients due to differences in thermal mass of SMD package may sill exist.
- Note 5: Components intended for use in a "lead-free" assembly process **shall** be evaluated using the "lead free" classification temperatures and profiles defined in Table-I II III whether or not lead free.

RoHS Compliant

The product does not contain lead, mercury, cadmium, hexavalent chromium, polybrominated biphenyls (PBB) or polybrominated diphenyl ethers (PBDE), and are therefore considered RoHS compliant.

ESD Sensitivity

Integrated circuits are ESD sensitive and can be damaged by static electricity. Proper ESD techniques should be used when handling these devices.



11. Change List

REV	DATE	AUTHER	CHANGE DESCRIPTION
v1.0e	2009-06-24	Hao Shi	Original draft.
v1.1e	2009-10-10	Ge Liu	V1.1 original draft
v1.2e	2009-12-11	Ge Liu	Add 200M~260MHz

12. Contact Information

RDA Microelectronics (Shanghai), Inc.

Suite 1108 Block A, e-Wing Center, 113 Zhichun Road Haidian District, Beijing

Tel: 86-10-62635360

Fax: 86-10-82612663

Postal Code: 100086

The information contained herein is the exclusive property of RDA and shall not be distributed, reproduced, or disclosed in whole or in part without prior written permission of RDA. Page 16 of 16